

# ECE606: Solid State Devices

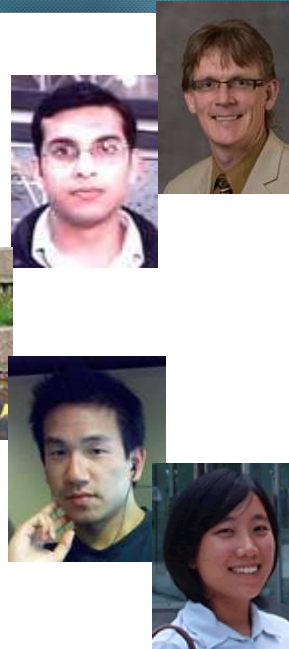
## Lecture 1

Gerhard Klimeck  
[gekco@purdue.edu](mailto:gekco@purdue.edu)

**PURDUE**  
UNIVERSITY



- **Gerhard Klimeck**
  - » Prof. at Purdue for 8 years
  - » Principal at NASA/JPL, 6 years
  - » Texas Instruments, 4 years
  - » Over 340 papers on devices/physics
- **Parijat Sengupta**
  - » 5<sup>th</sup> year graduate student
- **Yaohua Tan**
  - » 5<sup>th</sup> year graduate student
- **Matthias Yui-Hong Tan**
  - » 3<sup>rd</sup> year graduate student
- **Yuling Hsueh**
  - » 2<sup>nd</sup> year graduate student



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### Books

- Advanced Semiconductor Fundamentals (QM, SM, Transport) first 5 weeks
- Semiconductor Device Fundamentals (Diode, Bipolar, MOSFET) Weeks 6-15

### HW/Exams

- HW (9 HW, all will be graded; solutions will be provided; distributed every Tuesday, due at the beginning of the lecture)
- 3 exams (~5 weeks apart)

### Website

- <http://cobweb.ecn.purdue.edu/~ee606/>
- <https://blackboard.purdue.edu> (grades and optional notes)
- <https://nanohub.org/resources/5749> (full course on-line from Spring 2009)

### Office hours

- Klimeck: 1:30-2:30 Tue @EE 323, Thu 4:30pm-5:30pm @EE323



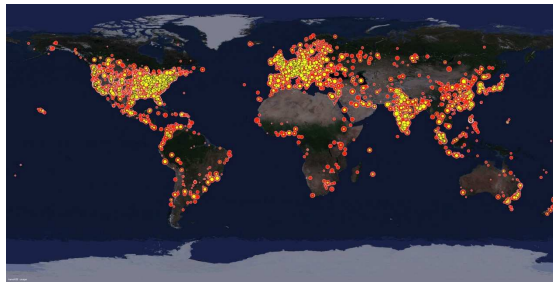
### Klimeck

- Leads the Network for Computational Nanotechnology (NCN)
- NCN hosts nanoHUB.org
- >230,000 users
- 172 countries
- ~15 professional staff
- 5 other universities

>3,000 resources on line

**Also THIS WHOLE course**  
[nanohub.org/resources/5749](http://nanohub.org/resources/5749)

Or search for “nanohub 606”

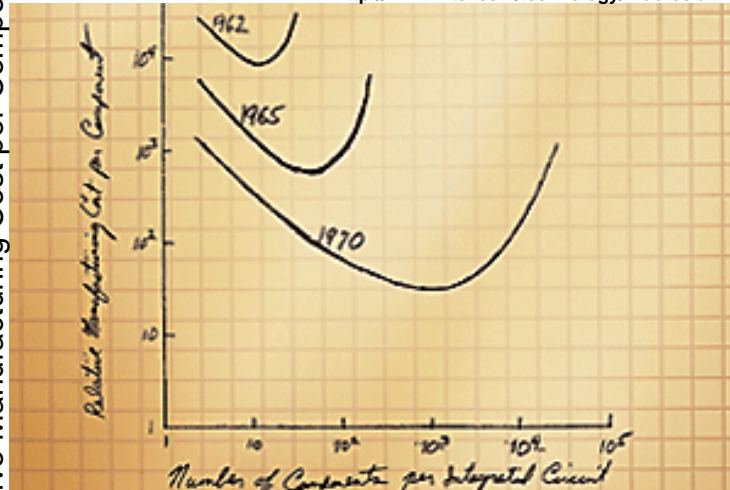


- Course information
- Motivation for the course
- Current flow in semiconductors
- Types of material systems
- Classification of crystals
  - » Bravais Lattices
  - » Packing Densities
  - » Common crystals - Non-primitive cells
    - ✓ NaCl, GaAs, CdS
  - » Surfaces
  
- Reference: Vol. 6, Ch. 1
- Helpful software: Crystal Viewer in ABACUS tool at nanohub.org

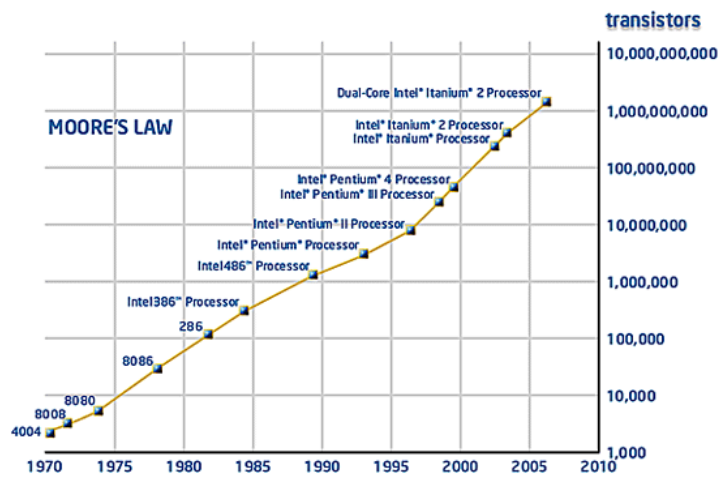


Relative Manufacturing Cost per Component

<http://www.intel.com/technology/mooreslaw>

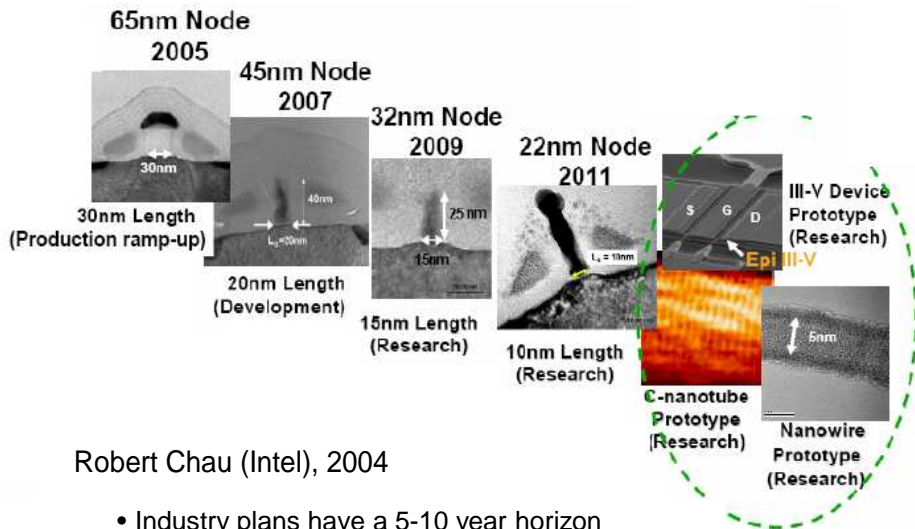


Number of Components per Integrated Circuit



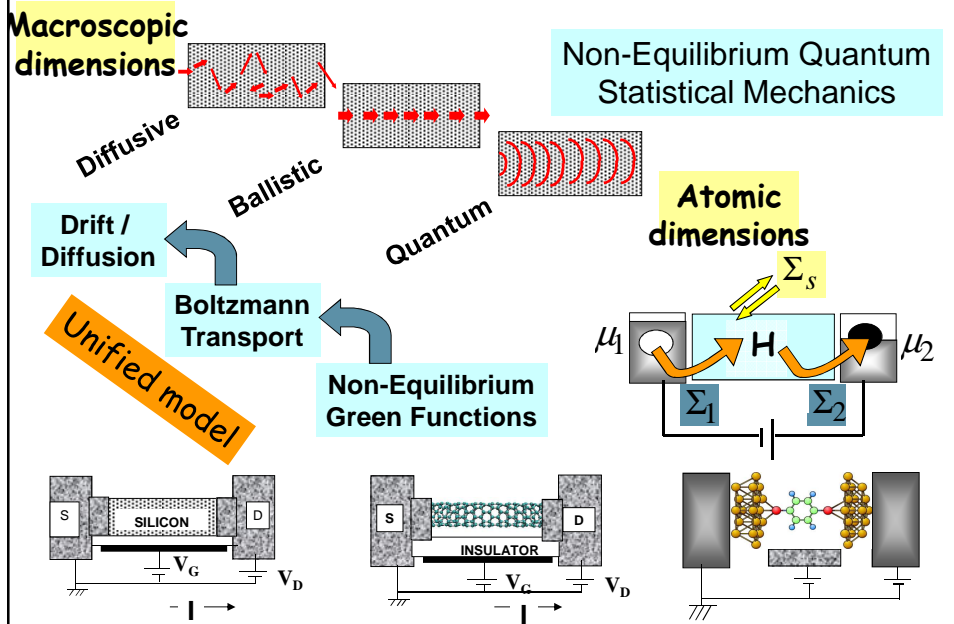
• From <http://www.intel.com/technology/mooreslaw/index.htm>





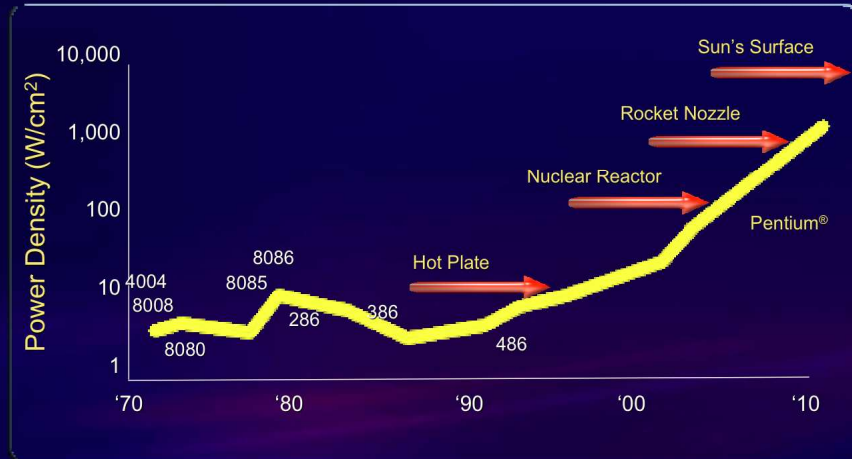
Robert Chau (Intel), 2004

- Industry plans have a 5-10 year horizon
  - Industry has been on time:
  - 32nm node predicted in 2004 and announced 2009
- There are **NO technically viable solutions beyond 2015**



# Today's CPU Architecture

## Heat becoming an unmanageable problem



Intel Developer Forum, Spring 2004 - Pat Gelsinger



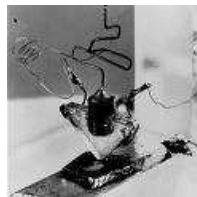
## Grand Challenges in Electronics

Vacuum Tubes



1906-1950s

Bipolar



1947-1980s

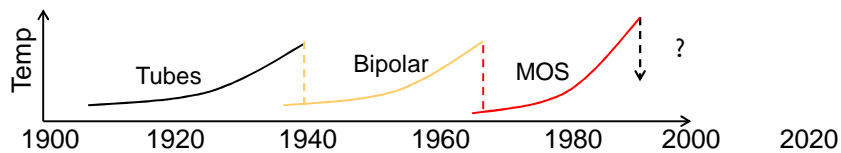
MOSFET

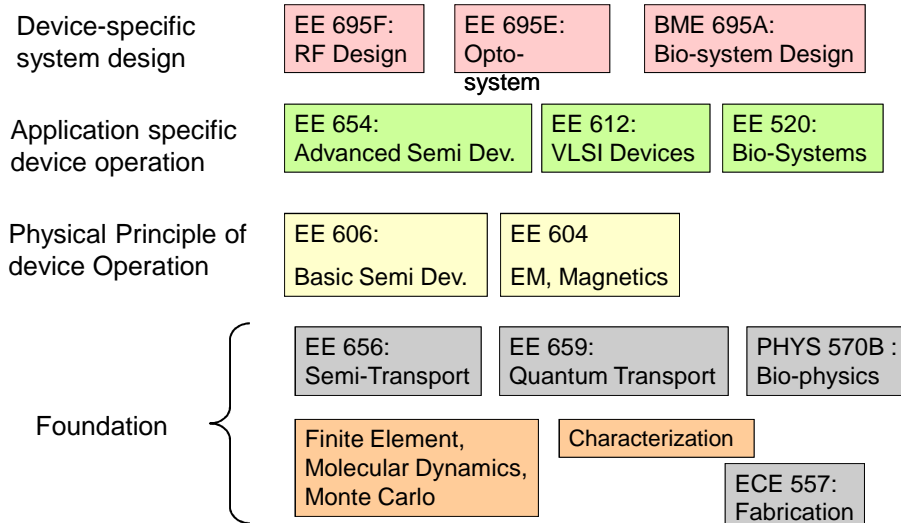
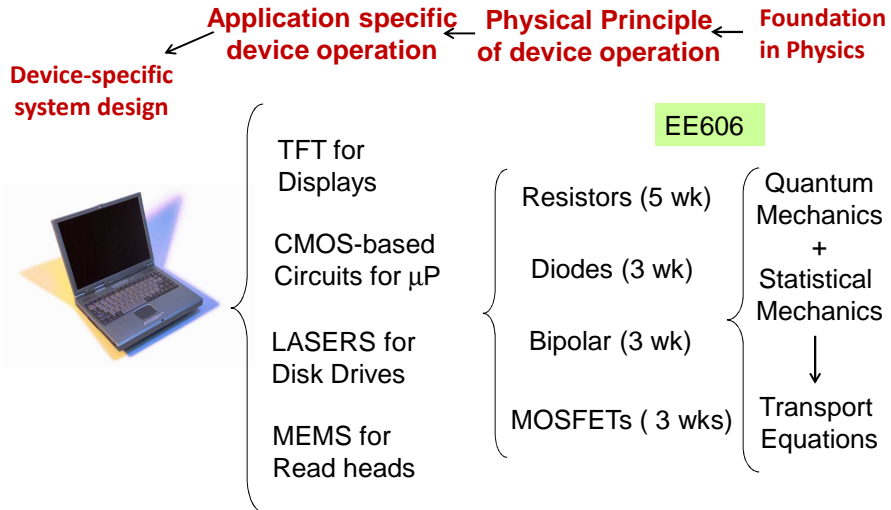


1960-until now

Now ??

Spintronics  
Bio Sensors  
Displays ....





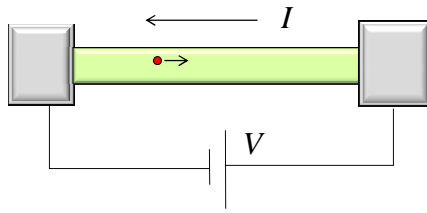
- Define “the language”
  - » Specialty area in ECE: MN - Micro – Nano – Electronics
  - » Bridge different communities, Electrical Engineering, Physics
- Fundamentals of Semiconductor Devices
  - » How to “think” about electrons in a semiconductor
  - » Foundation of typical job interviews –
    - ✓ technical interviews will typically not go into more detail
    - ✓ Probe the fundamental understanding of electronic behavior in Semiconductor
  - => Your entry into a technical job in Semiconductor Industry
  - » Required knowledge in the MN area Qualifying Exam
  - => Your entry into the PhD program in the MN area



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$$I = G \times V$$

$$= q \times n \times v \times A$$

Carrier Density      velocity

Depends on chemical composition, crystal structure, temperature, doping, etc. Could be tabulated for "known" materials. Need a theory for engineering of new devices/materials

### Quantum Mechanics + Equilibrium Statistical Mechanics

- Encapsulated into concepts of effective masses and occupation factors (Ch. 1-4)

### Transport with scattering, non-equilibrium Statistical Mechanics

- Encapsulated into drift-diffusion equation with recombination-generation (Ch. 5 & 6)



## Atomic composition

- number of electrons per atom

## Arrangement of atoms

- not all electrons are available for conduction

## For Periodic Arrays

- simplification for computation

- Concept of Unit Cells
- Simple 3-D Unit Cells



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↓	↓	↓	↓	↓
II	III	IV	V	VI
4 Be	5 B	6 C	7 N	8 O
12 Mg	13 <b>Al</b>	14 <b>Si</b>	15 <b>P</b>	16 S
30 <b>Zn</b>	31 <b>Ga</b>	32 Ge	33 <b>As</b>	34 <b>Se</b>
48 Cd	49 In	50 Sn	51 Sb	52 Te
80 Hg	81 Tl	82 Pb	83 Bi	84 Po

Si: \$260billion industry

**Elemental** (e.g., Si, Ge, C)

**Compound**

IV-IV: Si-Ge, Si-C

SiGe: stressors  
SiC: radiation

III-V: InP, GaAs,

Lasers/detectors

$(\text{In}_x\text{Ga}_{1-x})(\text{As}_y\text{P}_{1-y})$  expensive

II-VI: CdTe

Far IR detectors  
Soft and difficult

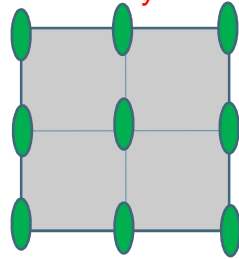
IV-VI: PbS

First semiconductor diodes  
Very soft and difficult

Not all combinations possible:  
lattice mismatch, room temp. instability, etc. are concerns

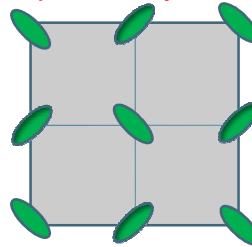


**solid crystals**



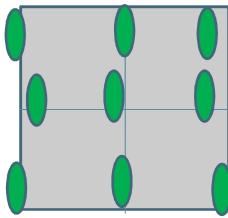
specific position  
specific orientation

**plastic crystals**



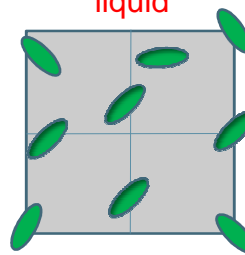
specific position  
random orientation

**liquid crystals**



random position  
specific orientation

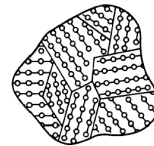
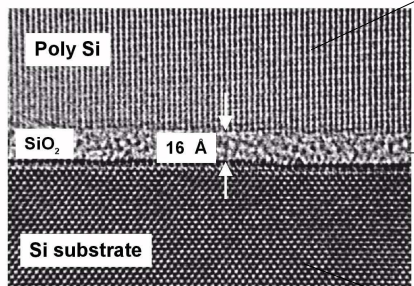
**liquid**



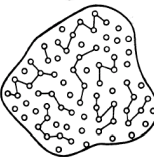
random position  
random orientation



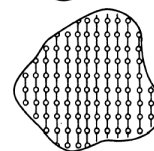
Cross section of a MOSFET



Poly-crystalline  
Thin Film  
Transistors



Amorphous  
Oxides  
*Why ?*



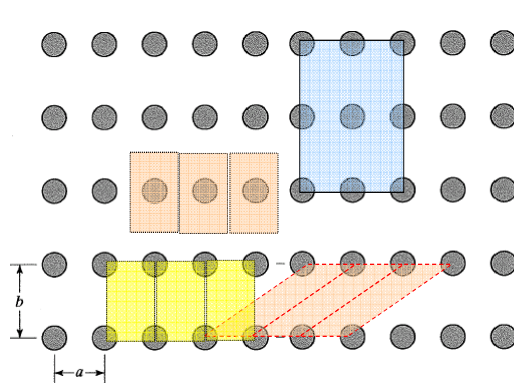
Perfectly arranged Si Crystal

Crystalline  
*Definition ?*

- Quantitative definition: Correlation spectrum and diffraction pattern
- Modern solid state devices use all forms these forms of materials
- Focus on Crystals first - relatively simple
- Transfer knowledge of electronic behavior in crystals to other materials



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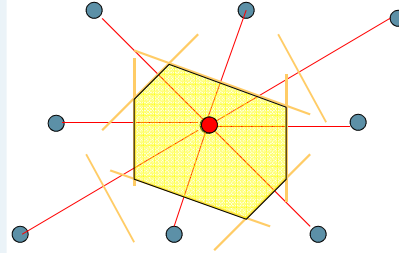
“Infinitely” extended  
2D shown  
3D same concepts

- ⇒  $N_A = 6 \times 10^{23}/\text{mol}$
- ⇒ Can NEVER solve this, even on the largest computer
- ⇒ Simplify to a repeated (small) cell

- Unit cells are *not* unique
- Unit cells can be Primitive or Non-primitive
- Property of ONE CELL defines the property of the solid



- Choose a reference atom
- Connect to all its neighbors by straight lines
- Draw lines (in 2D) or planes (in 3D) normal to and at the midpoints of lines drawn in step 2
- Smallest volume enclosed is the Wigner-Seitz primitive cell

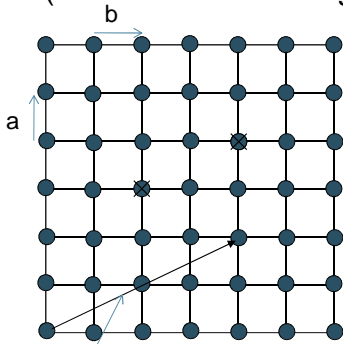


Wigner-Seitz cell is ONE definition of a Unit Cell  
that always works  
There are other ways of construction!

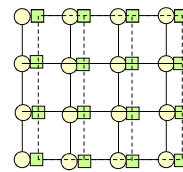


In a Bravais lattice,

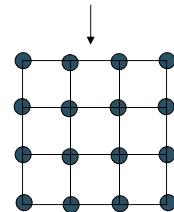
- every point in the lattice can be “reached” by *integer* translation of unit vectors
- every point has the same environment as every other point (same number of neighbors, next neighbors, ...)



$$\vec{R} = h\vec{a} + k\vec{b}$$

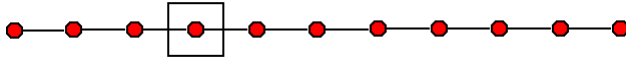


Non-Bravais lattice



Bravais lattice  
with a basis





There is exactly ONE primitive unit cell in a 1D system

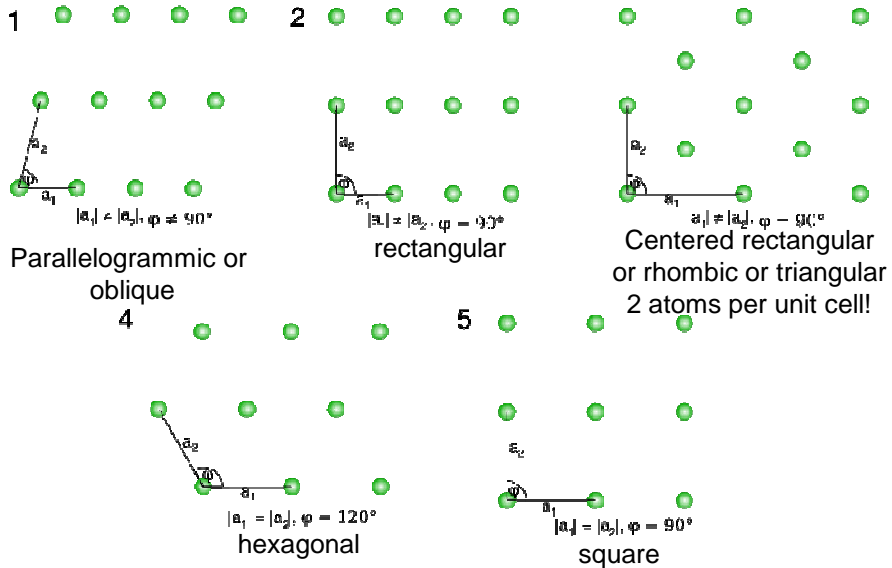
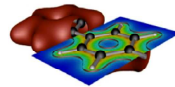
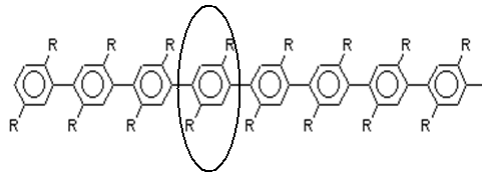
No system truly 1-D, but ....

- 1D properties dominate behavior in some material
  - e.g.: polymers, DNA, 1D heterostructures (lasers, RTDs)
- Can often be solved analytically, many properties have 2D/3D analogs

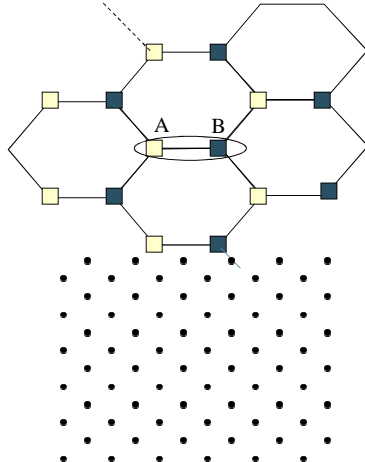
Polyacetylene



PPP



A and B do not have identical environments



This is a Graphene sheet which has recently been isolated from Graphite by adhesive tape stamping.

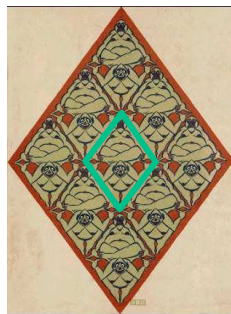
Ref. Novoselov, Geim, et al. Nature, 438, 197, 2005.

Conversion into a Bravais lattice:  
-Combine A and B into a single basis  
-Obtain a rhombic Bravais lattice

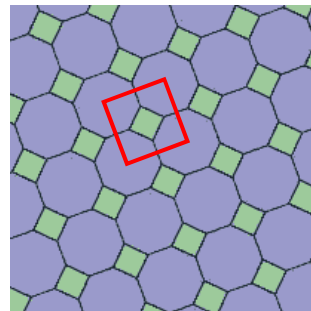
Original image from: [http://en.wikipedia.org/wiki/File:Rhombic\\_Lattice.svg](http://en.wikipedia.org/wiki/File:Rhombic_Lattice.svg)



Escher Tiling



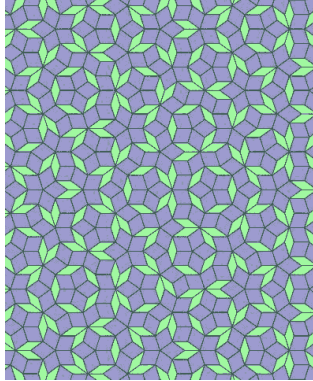
Kepler Tiling



...but these can be converted into Bravais lattice



Penrose Tiles



Ancient Tiles



Two different unit cells in **random order**

... these **CANNOT** be transformed to Bravais lattice  
ex. Aluminum-Manganese compounds, non-sticky coats



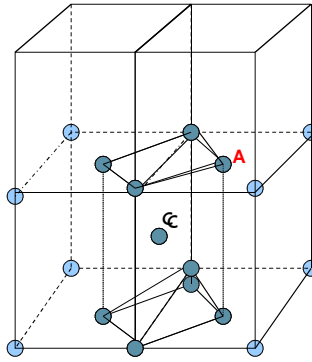
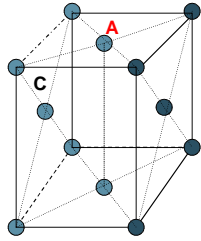
	Rotation						
points	Triclinic	Cubic	Tetragonal	Orthorhombic	Rhombohedral	Hexagonal	Monoclinic
<b>P</b> primitive	$\alpha, \beta, \gamma \neq 90^\circ$ 	$a = b = c$ 	$a \neq c$ 	$a \neq b \neq c$ 	$\alpha, \beta, \gamma \neq 90^\circ$ 	$a \neq c$ 	$\alpha \neq 90^\circ$ $\beta, \gamma = 90^\circ$ 
<b>I</b> Body centered			$a \neq c$ 	$a \neq b \neq c$ 			
<b>F</b> Face centered				$a \neq b \neq c$ 			
<b>C</b> Single face centered				$a \neq b \neq c$ 			$\alpha \neq 90^\circ$ $\beta, \gamma = 90^\circ$ 



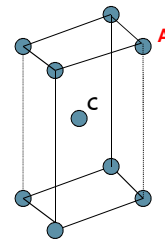


Unlucky Frankenheim (1842)  
counted 15 unit cells!  
Bravais pointed out that  
2 cells were duplicated

Tetragonal face centered



Tetragonal body centered



Tetragonal FC = Tetragonal BC



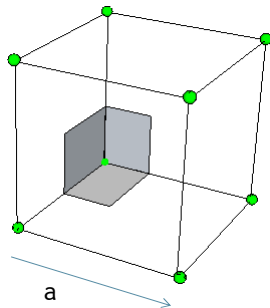
	Triclinic	Cubic	Tetragonal	Orthorhombic	Rhombohedral	Hexagonal	Monoclinic
P	$\alpha, \beta, \gamma \neq 90^\circ$ 		$a \neq c$ 	$a \neq b \neq c$ 	$\alpha, \beta, \gamma \neq 90^\circ$ 	$a \neq c$ 	$\alpha \neq 90^\circ$ $\beta, \gamma = 90^\circ$ 
I							
F							
C				$a \neq b \neq c$ 			$\alpha \neq 90^\circ$ $\beta, \gamma = 90^\circ$ 

Cubic conceptually simple,  
but experimentally very unusual  
Polonium84

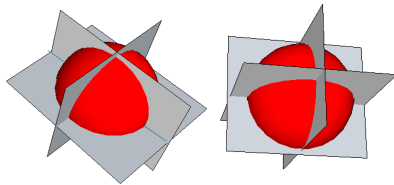
70-75% of all natural  
crystalline materials



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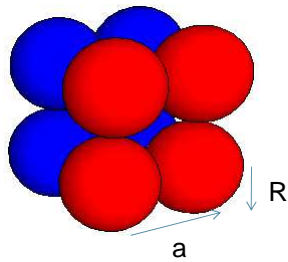
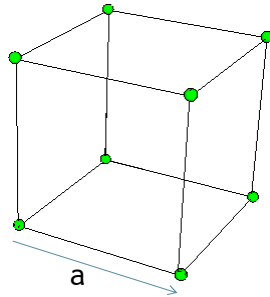


**Points per cell**  
 $= 1/8 \text{ points/corner} \times 8 \text{ corners}$   
 $= 1 \text{ Point/cell}$   
 (depends on definition of cell)



**Number density**  
 $= (1/a^3) \text{ points/cm}^3$   
 (does not depend on cell definition)





**Packing density**  
= volume filled / total volume

$R = a/2$  maximum radius  
 $V = (4/3)\pi R^3$  Volume of a sphere

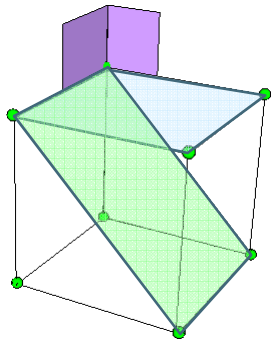
$P = (1/8) \times (4/3)\pi R^3 \times (8 \text{ corners}) / a^3$

$= \pi/6$

$\sim 52\%$

(about HALF of the volume is EMPTY)  
Typical for crystals and amorphous materials

(does not depend on cell definition)



Surfaces are critical in semiconductors:

- Vertical stacking of materials

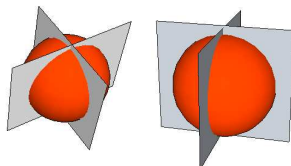
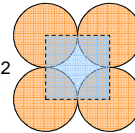
=> misalignment => dangling bonds => loose electrons

=> Different surface chemistry

**Areal Density**

$= (1/4 \text{ per corner}) \times (4 \text{ corners}) / a^2$

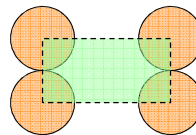
$= 1/a^2 \text{ cm}^{-2}$

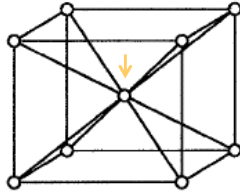


**Areal density (face diagonal)**

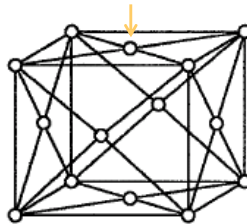
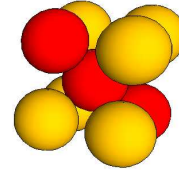
$= (1/4 \text{ points/corner}) \times (4 \text{ corners}) / \sqrt{2} a^2 \text{ cm}^{-2}$

$\sim 0.7/a^2 \text{ cm}^{-2}$

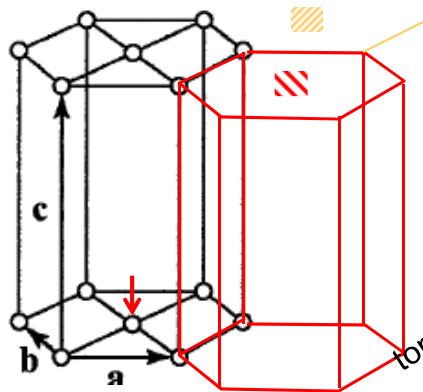
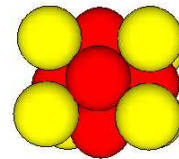




Points per cell  
 =  $1/8 \times 8$  @corners  
 + 1 @inside  
 = 2

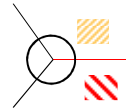


Points per cell  
 =  $1/8 \times 8$  @corners  
 +  $1/2 \times 6$  @faces  
 = 4



Points per cell

$1/2 \times 2$  @faces = 1



$1/2 \times 1/3 \times 12$  @corners = 2

top/bottom  
neighbors

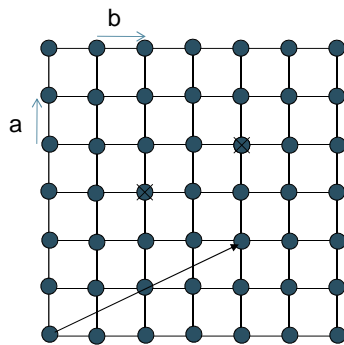
3 points/cell



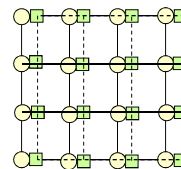
- Course information
- Motivation for the course
- Current flow in semiconductors
- Types of material systems
- **Classification of crystals**
  - » Bravais Lattices
  - » Packing Densities
  - » Common crystals - Non-primitive cells
    - ✓ NaCl, GaAs, CdS
  - » Surfaces
- Reference: Vol. 6, Ch. 1
- Helpful software: Crystal Viewer in ABACUS tool at nanohub.org



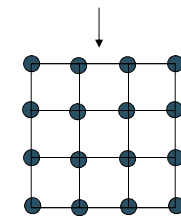
In a Bravais lattice, every point has the same environment as every other point (same number of neighbors, next neighbors, ...)



$$\vec{R} = h \vec{a} + k \vec{b}$$



Non-Bravais lattice

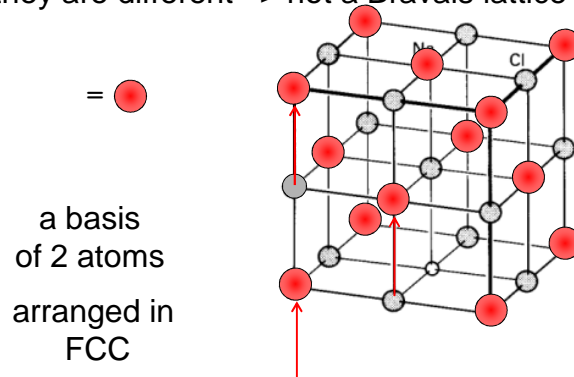


Bravais lattice with a basis



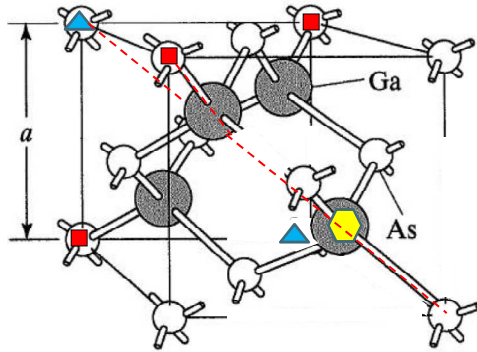


NaCl is normal household cooking salt  
 We see the crystals every day – what is the crystal structure?  
 At first glance it looks like a simple cubic cell  
 ⇒ one atom on each corner  
 ⇒ But they are different ⇒ not a Bravais lattice



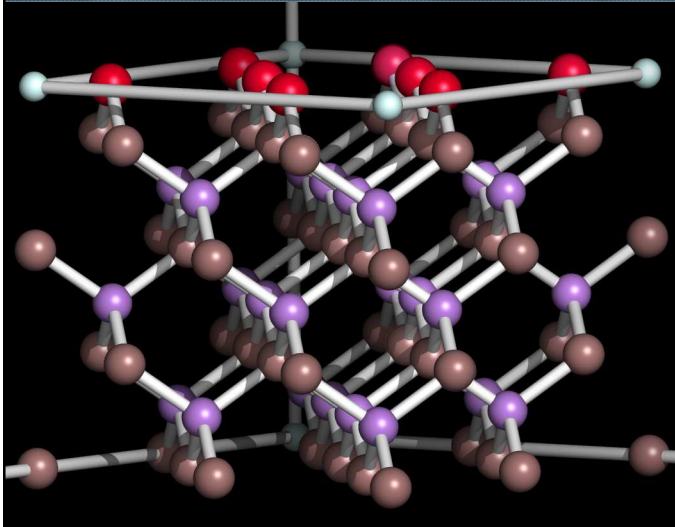
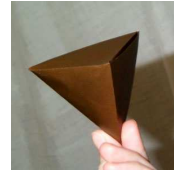
For more discussion, see Kittel and Ashcroft/Mermin

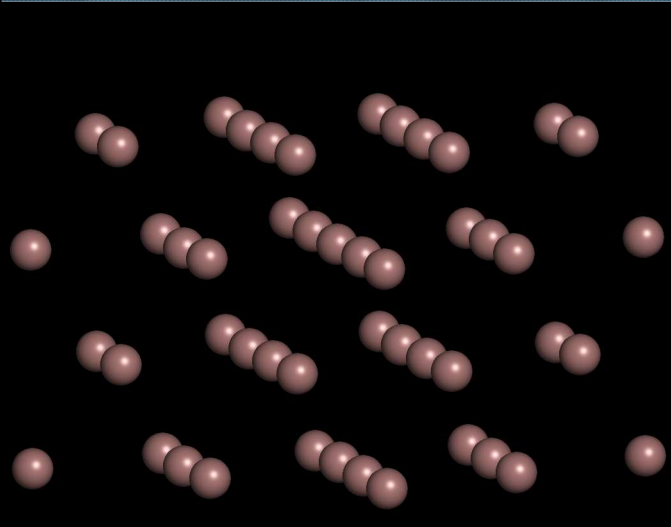
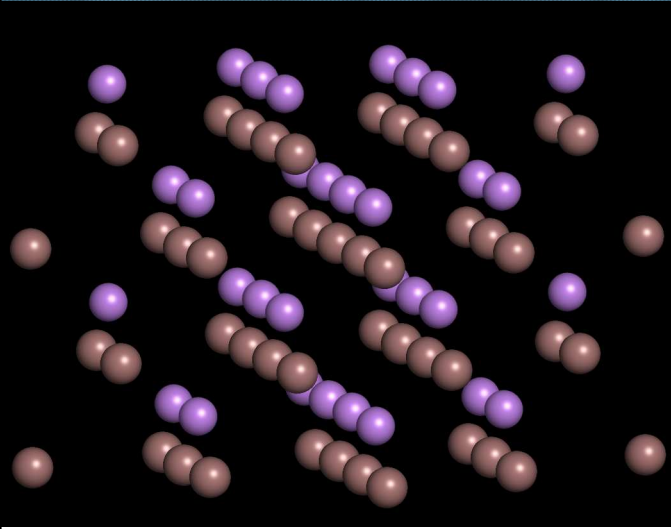




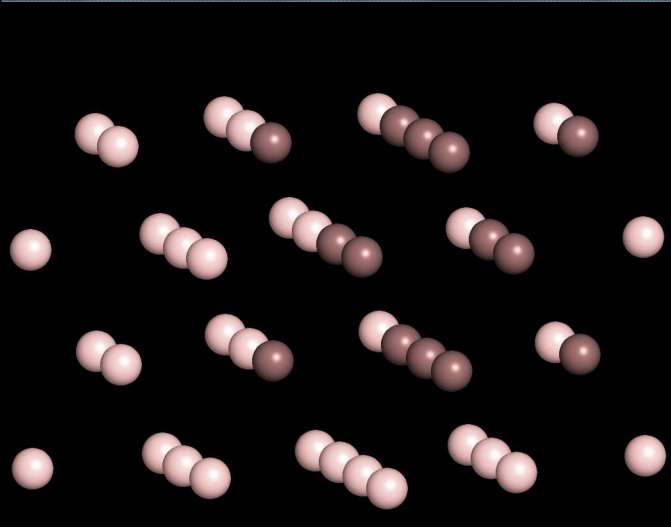
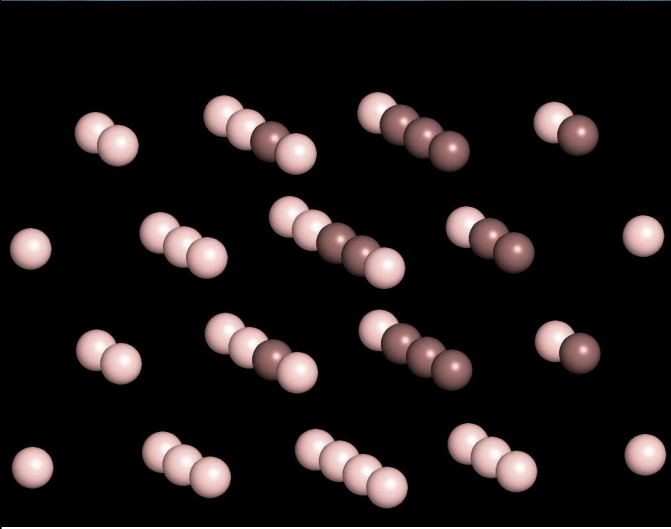
$$\text{Atoms/cell} = (1/8) \times 8 + (1/2) \times 6 + 4 = 8$$

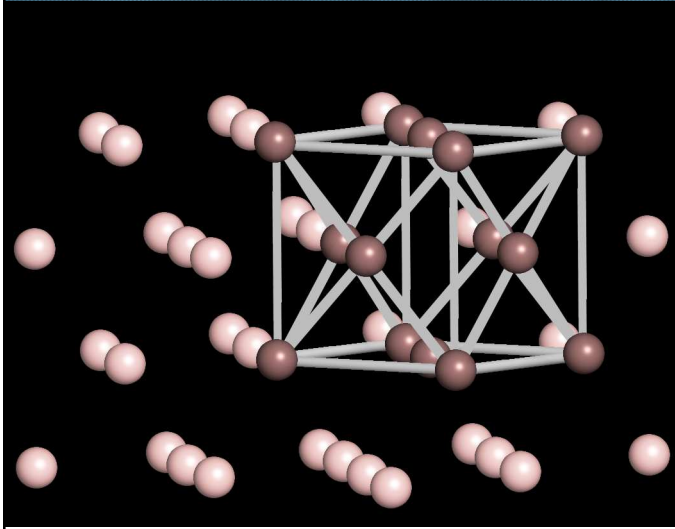
Tetrahedral structure



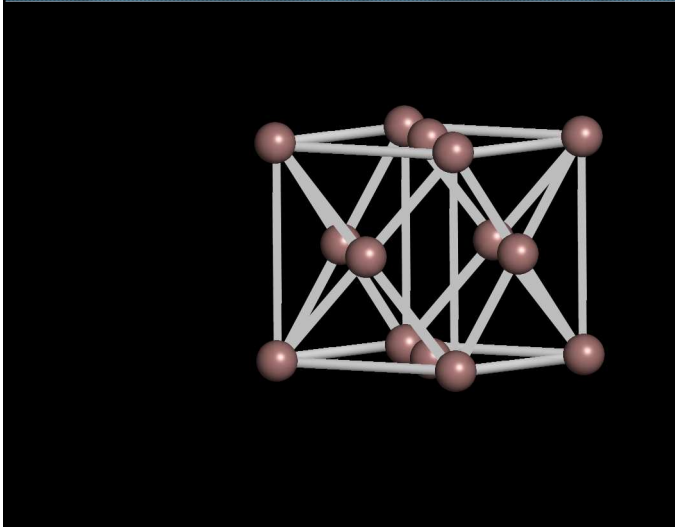






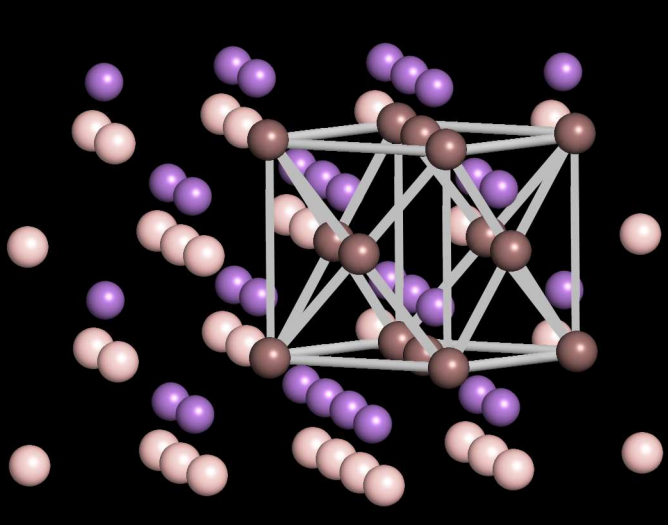


- FCC cell – 4 atoms per unit cell

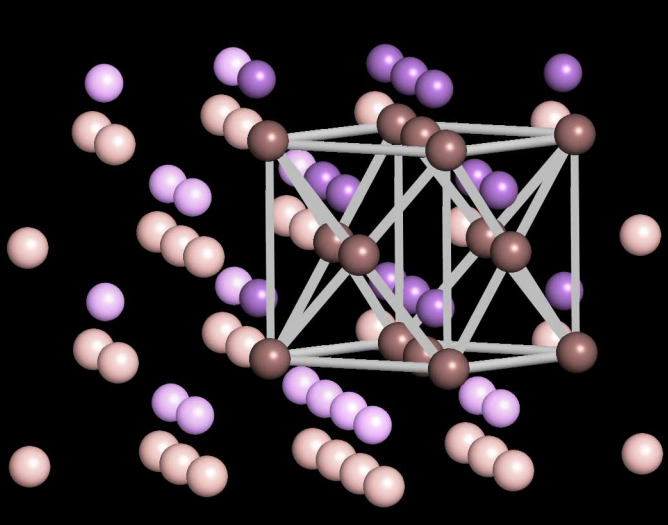


- FCC cell – 4 atoms per unit cell



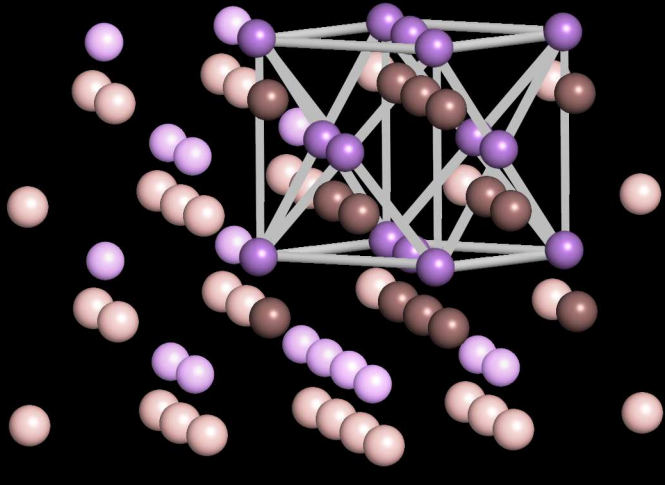


- FCC cell – 4 atoms per unit cell – brown species

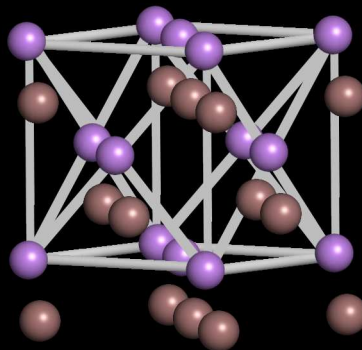


- FCC cell – 4 atoms per unit cell – brown species
- Focus on a few of the “blue species”



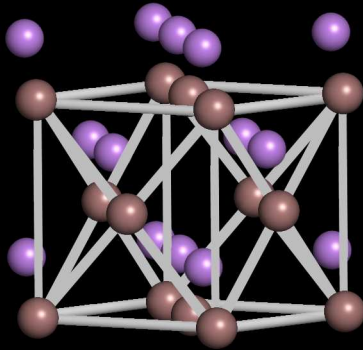


- FCC cell – 4 atoms per unit cell – brown species
- FCC cell – 4 atoms per unit cell – purple species

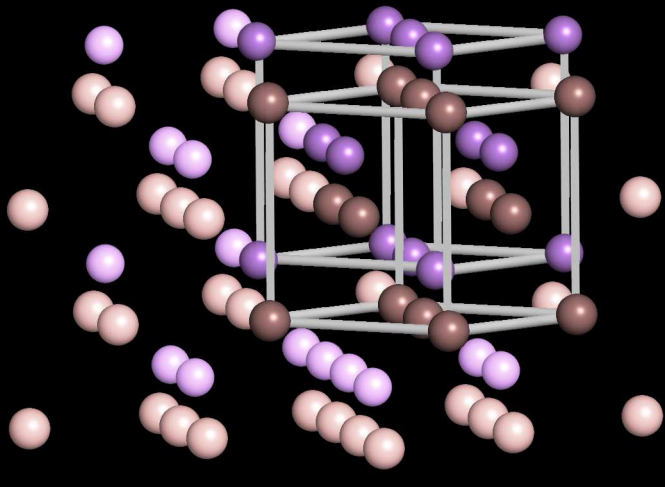


- FCC cell – 4 atoms per unit cell – brown species
- FCC cell – 4 atoms per unit cell – purple species



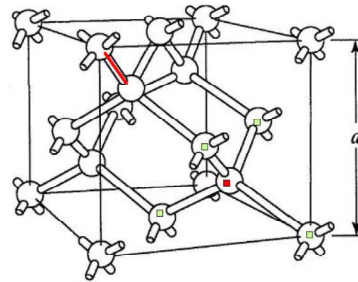
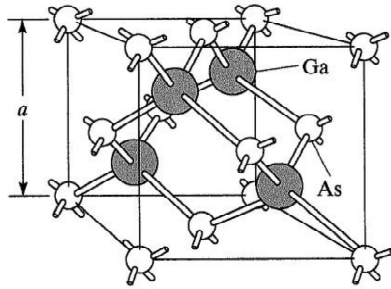


- FCC cell – 4 atoms per unit cell – brown species
- FCC cell – 4 atoms per unit cell – purple species

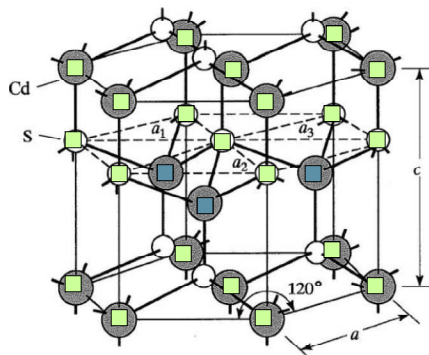


- Zincblende – 2 FCC bases – separated by  $[\frac{1}{4} \frac{1}{4} \frac{1}{4}]$

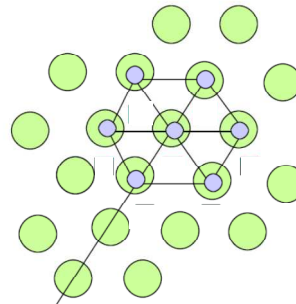




- Zincblende – GaAs - 2 FCC bases – separated by  $[\frac{1}{4} \frac{1}{4} \frac{1}{4}]$
- Diamond – Si - 2 FCC bases – separated by  $[\frac{1}{4} \frac{1}{4} \frac{1}{4}]$



Focus on (Cd) ...



$$\text{(Cd) atoms/cell} = (1/6) \times 12 + (1/2) \times 2 + 3 = 6$$



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